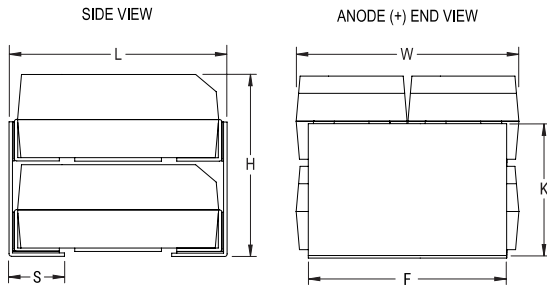


TSM, Tantalum, MnO2 Tantalum, HRA, 180 uF, 10%, 25 VDC, 4D



General Information	
Series:	TSM
Dielectric:	MnO2 Tantalum
Style:	Stacked Chip
Description:	SMD, MnO2, Stacks, High Reliability
Features:	High Reliability
RoHS:	Yes
Termination:	Tin
AEC-Q200:	No
MSL:	1

Dimensions	
Case Code	4D
L	8mm +/-0.38mm
W	8.9mm +/-0.2mm
H	6.2mm +/-0.38mm
S	1.9mm +/-0.38mm
F	7.4mm +/-0.2mm
K	4.8mm +/-0.38mm

Specifications	
Capacitance:	180 uF
Capacitance Tolerance:	10%
Voltage DC:	25 VDC (85C), 16.75 VDC (125C)
Temperature Range:	-55/+125°C
Rated Temperature:	85°C
Dissipation Factor:	10% 120Hz 25C
Failure Rate:	N/A
Resistance:	0.03 Ohms (100kHz 25C)
Leakage Current:	47.2 uA (5min 25°C)
Testing and Reliability:	Standard Testing Only

Packaging Specifications	
Packaging:	Tray
Packaging Quantity:	50

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